ASSP

TIMING EXTRACTION BANDPASS FILTER (1.5 to 100MHz)

F1/F2/F3 SERIES

DESCRIPTION

The F1, F2 and F3 Series were developed as timing extraction filters for primary, secondary, and tertiary digital communication devices.

This new all-solid-state bandpass filter (BPF) uses a piezoelectric with a large electromechanical coefficient (lithium tantalate: LiTaO₃). The filter has a wide bandwidth, and is very stable.

FEATURES

- Wide frequency range 1.5 to 100MHz
- Wide fractional bandwidth (%): 0.1 to 2.5
- Low insertion loss: 6dB or less
- Excellent temperature characteristics: 1.5 to 35MHz: ±400ppm or less (0 to 60°C)
 - 36 to 100MHz: -30ppm/°C (0 to 60°C)
- Small frequency deviation $\Delta f_0 < \pm 500$ ppm eliminating the need for adjustment
- · Highly reliable hermetically sealed package
- Compatible with small 14-pin DIP IC

PACKAGE



■ PIN ASSIGNMENT

| (BOTTOM VIEW) | | | | | |
|---------------------|----------------|-----------------------|--|--|--|
| | | 01 70 | | | |
| | | | | | |
| | | | | | |
| Pin No. | Pin name | Description | | | |
| Pin No. 1 | Pin name IN | | | | |
| | | Description | | | |
| 1 | IN | Description Input pin | | | |

■ MAXIMUM RATINGS

| ltem | Symbol | Rating | Unit |
|-----------------------|--------|---------------|------|
| Operating temperature | Ta | -20 to 80 | °C |
| Storage temperature | Tstg | -40 to 80 | °C |
| Insulation resistance | IR | 100 (100V DC) | MΩ |
| Frequency range | | 1.5 to 100 | MHz |

■ RECOMMENDED OPERATING CONDITIONS

| ltem | Symbol | Rating | Unit |
|-----------------------|--------|---------|------|
| Operating temperature | Ta | 0 to 70 | °C |

■ STANDARD FREQUENCY

| Series | Standard frequency | Application | Remarks |
|--------|--------------------|--|-----------|
| | 1.544MHz | For the U.S. and Japan (primary group) | |
| | 2.048MHz | For Europe (primary group) | |
| | 3.088MHz | For the U.S. and Japan (primary group) | 1.544 × 2 |
| | 3.152MHz | For the U.S. and Japan (primary group) | |
| Γ4 | 4.096MHz | For Europe (primary group) | 2.048 × 2 |
| F1 | 6.312MHz | For the U.S. and Japan (secondary group) | |
| | 8.192MHz | For the U.S. and Japan (secondary group) | |
| | 8.448MHz | For Europe (secondary group) | |
| | 12.624MHz | For the U.S. and Japan (secondary group) | 6.312 × 2 |
| | 16.384MHz | For the U.S. and Japan (secondary group) | 8.192 × 2 |
| | 16.896MHz | For Europe (secondary group) | 8.448 × 2 |
| F2 | 32.064MHz | For Japan (tertiary group) | |
| | 34.368MHz | For Europe (tertiary group) | |
| F3 | 44.736MHz | For the U.S. (tertiary group) | |

■ ELECTRICAL CHARACTERISTICS

F1 Series

| Item | Symbol | Condition | Rating | | | Unit | Remarks |
|--------------------------------------|---------|------------------------|--------|---------|------|------|----------------------------------|
| | | | Min. | Typical | Max. | Unit | Remarks |
| Frequency deviation | Δfo | | -500 | | +500 | ppm | fo standard |
| Load Q | Q | | 1000 | | 40 | | |
| Insertion loss | IL | | | — | 6 | dB | |
| Stop band attenuation | Aout | $f_{\text{O}}\pm10MHz$ | 20 | — | | dB | |
| Frequency stability with temperature | ∆f (Ta) | | -400 | _ | +400 | ppm | 25°C standard, Ta = 0 to 70°C |

F2 Series

| ltem | Symbol | Condition | Rating | | | Unit | Remarks | |
|--------------------------------------|---------|------------------------|--------|---------|------|------|----------------------------------|--|
| | Symbol | Condition | Min. | Typical | Max. | Unit | itemarks | |
| Frequency deviation | Δfo | | -500 | — | +500 | ppm | fo standard | |
| Load Q | Q | | 1000 | — | 40 | | | |
| Insertion loss | IL | | | — | 6 | dB | | |
| Stop band attenuation | Аоит | $f_{\text{O}}\pm10MHz$ | 20 | — | | dB | | |
| Frequency stability with temperature | ∆f (Ta) | | -400 | | +400 | ppm | 25°C standard, Ta = 0 to 70°C | |

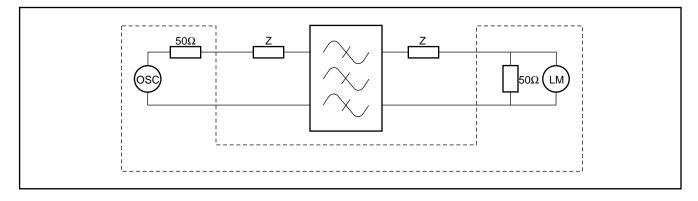
F3 Series

| ltem | Symbol | Condition | Rating | | | Unit | Remarks | |
|--------------------------------------|---------|--------------------------|--------|---------|------|------|----------------------------------|--|
| nem | Symbol | Condition | Min. | Typical | Max. | Unit | iteliidi k5 | |
| Frequency deviation | Δfo | | -500 | — | +500 | ppm | fo standard | |
| Load Q | Q | | 200 | — | 50 | | | |
| Insertion loss | IL | | | | 6 | dB | | |
| Stop band attenuation | Аоит | $f_{\text{O}}\pm 10 MHz$ | 20 | — | | dB | | |
| Frequency stability with temperature | ∆f (Ta) | | -1350 | | 750 | ppm | 25°C standard, Ta = 0 to 70°C | |

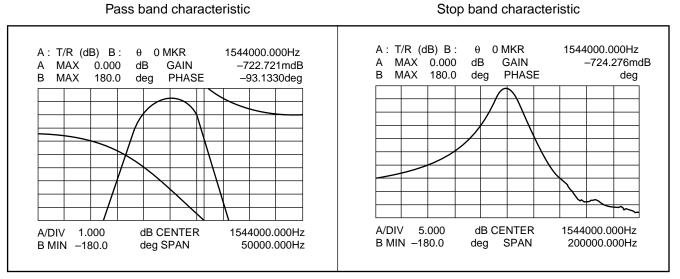
■ ELECTRICAL CHARACTERISTICS

| | Standard | | Specification | | | | | |
|-----|--------------------------------|----------------------|---------------|----------------------------|---------------------------------|-----------------------------------|--|--|
| No. | Standard frequency (MHz) | Part number | Load Q | Insertion loss, IL (dB) | Phase rotation θ (degree) | Terminating impedance Z (Ω) | | |
| 1 | 1.544 | FAR-F1DA-1M5440-G201 | 110 ±20 | 3 or less | -90±20 | 790 | | |
| 2 | 1.544 | FAR-F1DA-1M5440-G202 | 110 ±20 | 3 or less | -90±20 | 1000 | | |
| 3 | 1.544 | FAR-F1DA-1M5440-G203 | 60 ±10 | 3 or less | -95±10 | 2035/20pF | | |
| 4 | 1.544 | FAR-F1DA-1M5440-G205 | 110 ±20 | 3 or less | -90±20 | 2000 | | |
| 5 | 2.048 | FAR-F1DA-2M0480-G201 | 40 ±10 | 3 or less | -90±10 | 2035 | | |
| 6 | 2.048 | FAR-F1DA-2M0480-G202 | 100 ±20 | 3 or less | -90±20 | 1000 | | |
| 7 | 3.088 | FAR-F1DA-3M0880-G201 | 150 ±20 | 3 or less | -90±20 | 640 | | |
| 8 | 3.152 | FAR-F1DA-3M1520-G201 | 85 ±15 | 3 or less | -90±15 | 1285 | | |
| 9 | 4.096 | FAR-F1DA-4M0960-G201 | 110 ±20 | 3 or less | -90±20 | 750 | | |
| 10 | 6.312 | FAR-F1DA-6M3120-G201 | 110 ±20 | 3 or less | -90±20 | 985 | | |
| 11 | 6.312 | FAR-F1DA-6M3120-G202 | 110 ±20 | 3 or less | -90±20 | 1000 | | |
| 12 | 8.192 | FAR-F1DA-8M1920-G201 | 100 ±20 | 3 or less | -90±20 | 980 | | |
| 13 | 8.448 | FAR-F1DA-8M4480-G201 | 110 ±20 | 3 or less | -90±20 | 980 | | |
| 14 | 12.624 | FAR-F1DA-12M624-G201 | 100 ±20 | 3 or less | -90±20 | 590 | | |
| 15 | 16.384 | FAR-F1DA-16M384-G201 | 100 ±20 | 3 or less | -90±20 | 410 | | |
| 16 | 16.896 | FAR-F1DA-16M896-G201 | 100 ±20 | 3 or less | -90±20 | 390 | | |
| 17 | 32.064 | FAR-F2DA-32M064-G201 | 100 ±10 | 3 or less | -90±15 | 100 | | |
| 18 | 34.368 | FAR-F2DA-34M368-G201 | 100 ±10 | 3 or less | -90±15 | 100 | | |
| 19 | 44.736 | FAR-F3DA-44M736-G201 | 65 ±15 | 6 or less | 38±10 | 105 | | |

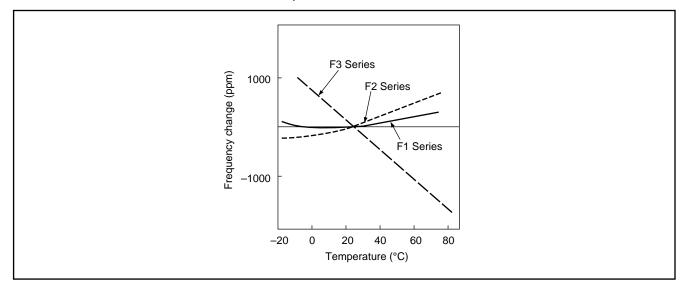
■ TEST CIRCUIT



CHARACTERISTICS SAMPLE



Temperature characteristic



PART NUMBERING SYSTEM

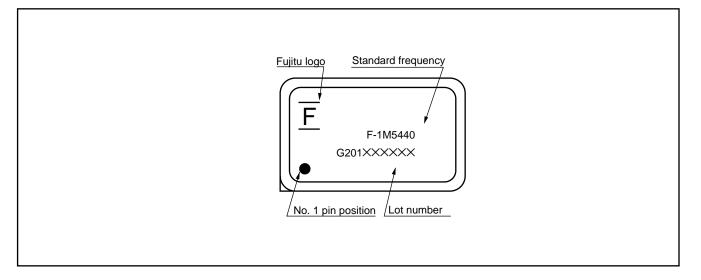
[Example]



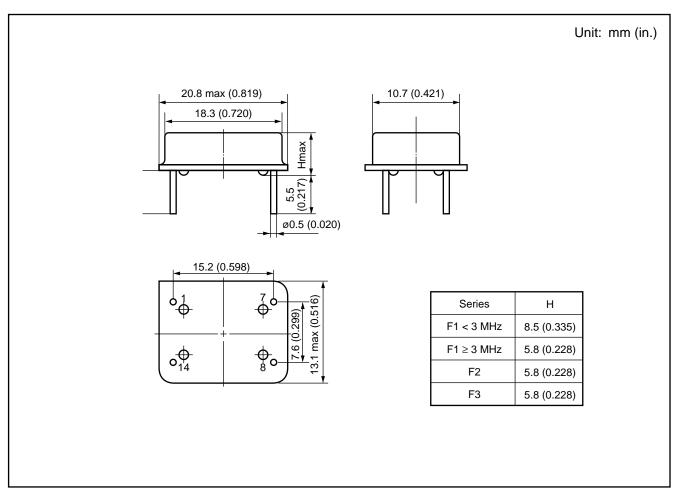
① Series designation

- ② Frequency designation: The standard frequency is designated in six alphanumeric characters. M is used to designate the decimal point in MHz. Refer to "ELECTRIC CHARACTERISTICS" in detail Example: 1.544MHz: 1M5440
- ③ Serial number: The serial number is assigned from 201 to 999 (201 is normal).

■ MARKING



■ DIMENSIONS



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